

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	632425	(pressure with chamber)	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 18:22
L2	14544	(pressure with chamber) with (insulat\$3 or dielectric or oxide)	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 18:34
L3	5628	2 and ((reduc\$3 or decreas\$3) with pressure)	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 18:34
L4	267	3 and second adj pressure	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 18:35
L5	3	4 and "Torr/sec"	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 18:35

EAST Search History

L6	70	3 and gradual\$3 with decreas\$3 with pressure	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 18:29
L7	22	6 and semiconductor	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 18:31
L8	3	7 and (raw adj material)	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 18:32
L9	8	7 and (inert)	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 18:32
L10	268	438/760.ccls.	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 18:33

EAST Search History

L11	625	438/784.ccls.	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 18:33
L12	1110	438/795.ccls.	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 18:33
L13	237	438/711.ccls.	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 18:33
L14	6	10 and (pressure with chamber) with (insulat\$3 or dielectric or oxide)	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 18:34
L15	27	11 and (pressure with chamber) with (insulat\$3 or dielectric or oxide)	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 18:34

EAST Search History

L16	34	12 and (pressure with chamber) with (insulat\$3 or dielectric or oxide)	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 18:34
L17	28	13 and (pressure with chamber) with (insulat\$3 or dielectric or oxide)	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 18:34
L18	3	14 and ((reduc\$3 or decreas\$3) with pressure)	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 18:34
L19	20	15 and ((reduc\$3 or decreas\$3) with pressure)	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 18:34
L20	21	16 and ((reduc\$3 or decreas\$3) with pressure)	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 18:35

EAST Search History

L21	20	17 and ((reduc\$3 or decreas\$3) with pressure)	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 18:35
L22	1	18 and "Torr/sec"	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 18:35
L23	1	19 and "Torr/sec"	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 18:35
L24	0	20 and "Torr/sec"	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 18:35
L25	0	21 and "Torr/sec"	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 18:35

EAST Search History

L26	2	18 and second adj pressure	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 18:35
L27	2	19 and second adj pressure	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 18:36
L28	2	20 and second adj pressure	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 18:35
L29	0	21 and second adj pressure	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 18:35